



**THE DATASHEET OF  
IR3876MTR1PBF**



# Sup/IRBuck™

## 12A HIGHLY INTEGRATED

## WIDE-INPUT VOLTAGE, SYNCHRONOUS BUCK REGULATOR

### Features

- Input Voltage Range: 3V to 21V
- Output Voltage Range: 0.5V to 12V
- Continuous 12A Load Capability
- Constant On-Time control
- Excellent Efficiency at very low output current levels
- Compensation Loop not Required
- Programmable switching frequency, soft start, and over current protection
- Power Good Output
- Precision Voltage Reference (0.5V, +/-1%)
- Pre-bias Start Up
- Under/Over Voltage Fault Protection
- Ultra small, low profile 5mm x 6mm QFN Package

### Description

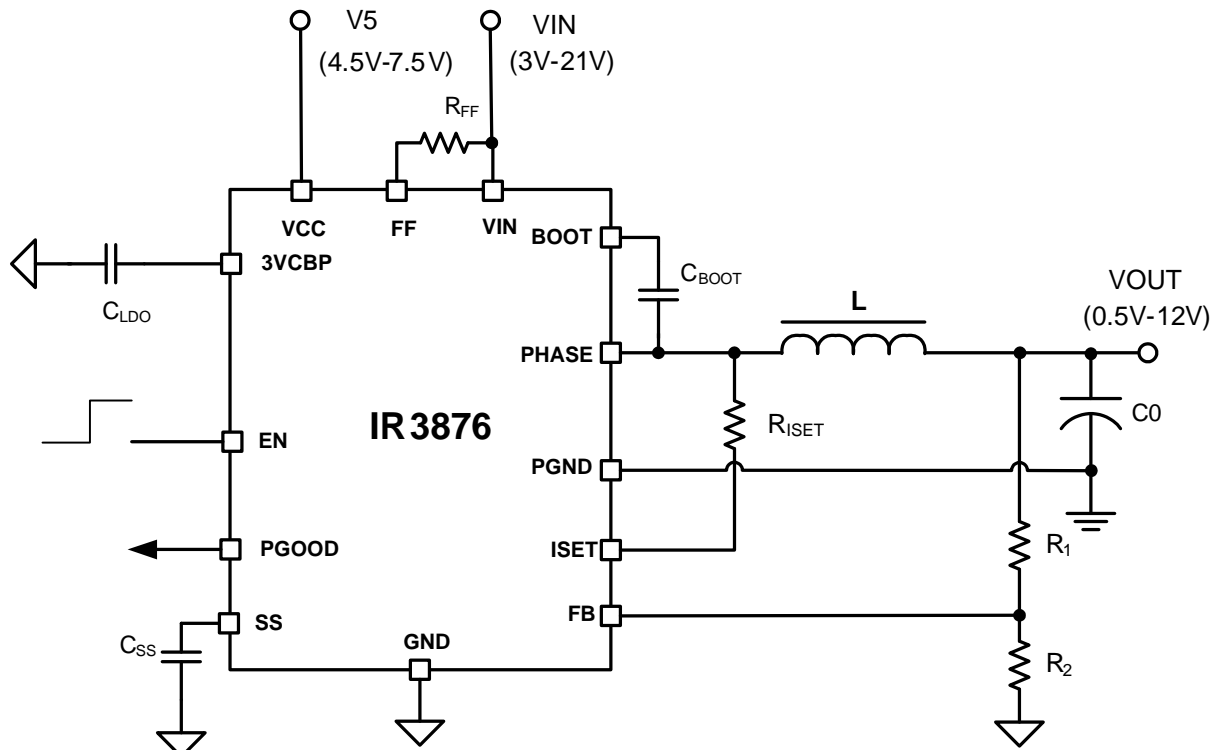
The IR3876 *SupIRBuck™* is an easy-to-use, fully integrated and highly efficient DC/DC voltage regulator. The onboard constant on time hysteretic controller and MOSFETs make IR3876 a space-efficient solution that delivers up to 12A of precisely controlled output voltage in 60°C ambient temperature applications without airflow.

Programmable switching frequency, soft start, and over current protection allows for a very flexible solution suitable for many different applications and an ideal choice for battery powered applications.

Additional features include pre-bias startup, very precise 0.5V reference, over/under voltage shut down, power good output, and enable input with voltage monitoring capability.

### Applications

- Notebook and desktop computers
- Game consoles
- Consumer electronics – STB, LCD, TV, printers
- General purpose POL DC-DC converters



**ABSOLUTE MAXIMUM RATINGS**

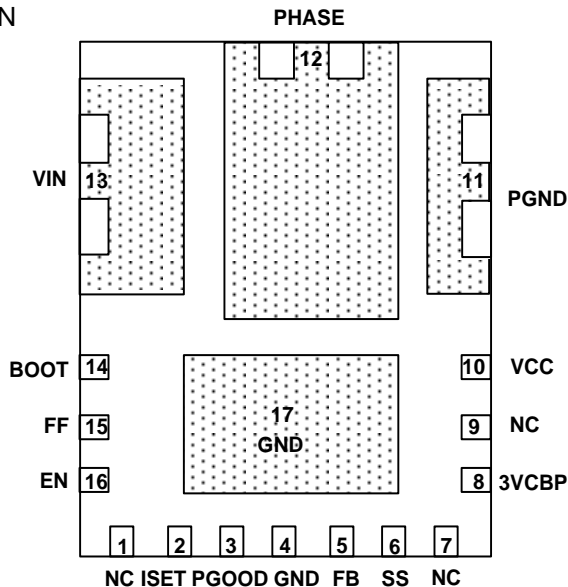
(Voltages referenced to GND unless otherwise specified)

- VIN, FF ..... -0.3V to 25V
- VCC, PGood, EN ..... -0.3V to 8.0V
- Boot ..... -0.3V to 33V
- PHASE ..... -0.3V to 25V(DC), -5V(100ns)
- Boot to PHASE ..... -0.3V to 8V
- ISET ..... -0.3V to 30V
- PGND to GND ..... -0.3V to +0.3V
- All other pins ..... -0.3V to 3.9V
- Storage Temperature Range ..... -65°C To 150°C
- Junction Temperature Range ..... -10°C To 150°C
- ESD Classification ..... JEDEC Class 1C
- Moisture sensitivity level ..... JEDEC Level 2 @ 260°C (Note 2)

*Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied.*

**PACKAGE INFORMATION**

5mm x 6mm POWER QFN



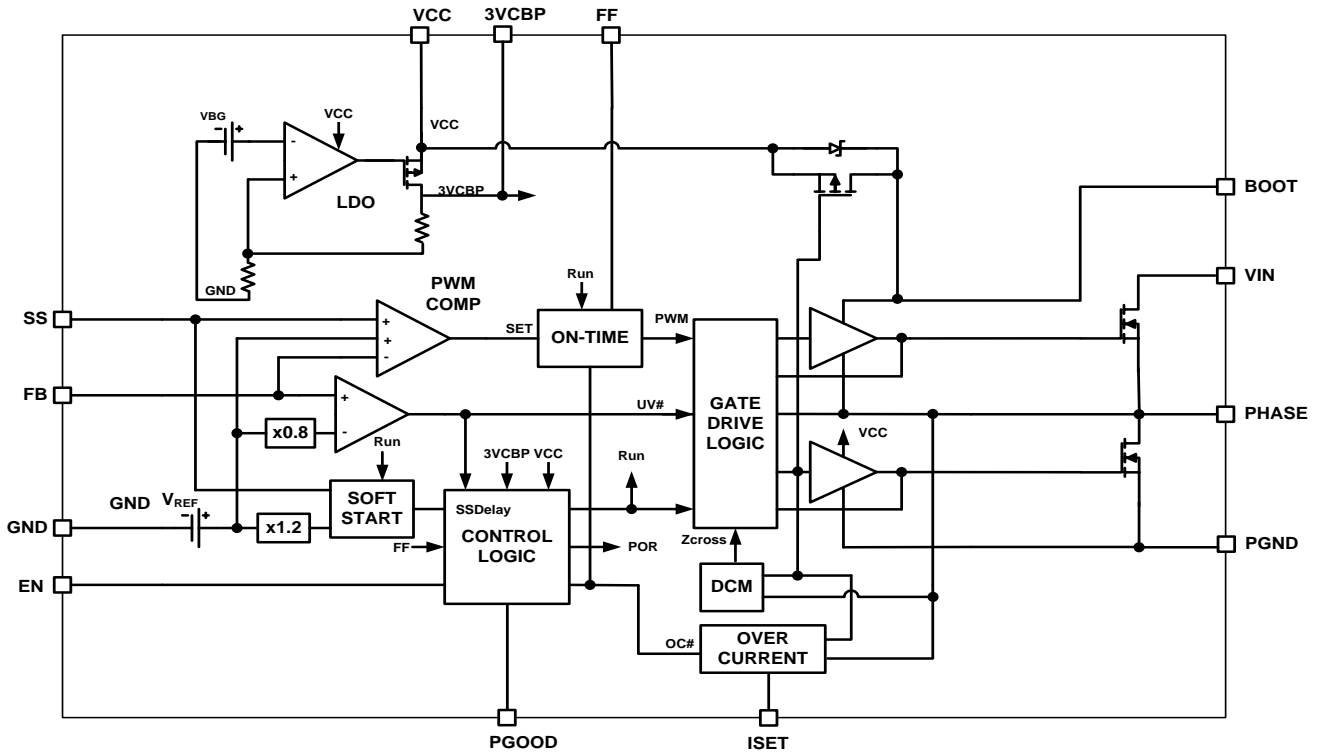
$$\theta_{JA} = 35^{\circ}\text{C} / \text{W}$$

$$\theta_{J-PCB} = 2^{\circ}\text{C} / \text{W}$$

**ORDERING INFORMATION**

PKG DESIG	PACKAGE DESCRIPTION	PIN COUNT	PARTS PER REEL
M	IR3876MTRPbF	17	4000
M	IR3876MTR1PbF	17	750

**Block Diagram**



## Pin Description

NAME	NUMBER	I/O LEVEL	DESCRIPTION
NC	1	-----	No connection
ISET	2		Connecting resistor to PHASE pin sets over current trip point
PGOOD	3	5V	Power good – pull up to 3.3V
GND	4,17	Reference	Bias return and signal reference
FB	5	3.3V	Inverting input to PWM comparator, OVP / PGood sense
SS	6	3.3V	Set soft start slew-rate with a capacitor to GND
NC	7	-----	No connection
3VCBP	8	3.3V	LDO output. A minimum of 1.0 $\mu$ F ceramic capacitor is required
NC	9	-----	No connection
VCC	10	5V	Gate drive supply
PGND	11	Reference	Power return
PHASE	12	VIN	Phase node (or switching node) of MOSFET half bridge
VIN	13	VIN	Input voltage for the system.
BOOT	14	VIN +VCC	Bootstrapped gate drive supply – connect a capacitor to PHASE
FF	15	VIN	Input voltage feed forward – sets on-time with a resistor to VIN
EN	16	5V	Enable

## Recommended Operating Conditions

Symbol	Definition	Min	Max	Unit
V <sub>IN</sub>	Input Voltage	3	21*	V
V <sub>CC</sub>	Supply Voltage	4.5	7.5	
V <sub>OUT</sub>	Output Voltage	0.5	12	
I <sub>OUT</sub>	Output Current	0	12	A
F <sub>s</sub>	Switching Frequency	N/A	1000	kHz
T <sub>J</sub>	Junction Temperature	0	125	°C

\* Note: PHASE pin must not exceed 25V.

## Electrical Specifications

Unless otherwise specified, these specification apply over V<sub>IN</sub> = 12V, V<sub>CC</sub> = 5V, 0°C ≤ T<sub>J</sub> ≤ 125°C.

PARAMETER	NOTE	TEST CONDITION	MIN	TYP	MAX	UNIT
<b>BIAS SUPPLIES</b>						
V <sub>CC</sub> Turn-on Threshold			3.9	4.2	4.5	V
V <sub>CC</sub> Turn-off Threshold			3.6	3.9	4.2	V
V <sub>CC</sub> Threshold Hysteresis				150		mV
V <sub>CC</sub> Operating Current		R <sub>FF</sub> = 200K, EN = HIGH, F <sub>s</sub> = 300kHz		9.2		mA
V <sub>CC</sub> Shutdown Current		EN = LOW		35	50	μA
FF Shutdown Current		EN = LOW		2		μA
V <sub>IN</sub> Shutdown Current		EN = LOW		1		μA
<b>INTERNAL LDO OUTPUT</b>						
LDO Output Voltage Range		C <sub>LDO</sub> = 1μF	3.1	3.3	3.5	V
Output Current					8	mA
<b>CONTROL LOOP</b>						
Reference Accuracy, V <sub>REF</sub>		V <sub>REF</sub>	0.495	0.5	0.505	V
On-Time Accuracy		R <sub>FF</sub> = 180K, T <sub>J</sub> = 65°C	280	300	320	ns
Min Off Time	1			400		ns
Soft-Start Current		EN = HIGH	8	10	12	μA
Zero Current Threshold	1	Measure at V <sub>PHASE</sub>	-5	-2.4	0	mV
<b>FAULT PROTECTION</b>						
ISET Pin Output Current			18	20	22	μA
Under Voltage Threshold		Falling V <sub>FB</sub> & Monitor PGOOD	0.37	0.4	0.43	V
Under Voltage Hysteresis	1	Rising V <sub>FB</sub>		10		mV
Over Voltage Threshold		Rising V <sub>FB</sub> & Monitor PGOOD	0.58	0.62	0.66	V
Over Voltage Hysteresis	1	Falling V <sub>FB</sub>		10		mV
PGOOD Delay Threshold (V <sub>SS</sub> )				1		V

**Electrical Specifications (continued)**

Unless otherwise specified, these specification apply over  $V_{IN} = 12V$ ,  $V_{CC} = 5V$ ,  $0^{\circ}C \leq T_J \leq 125^{\circ}C$ .

PARAMETER	NOTE	TEST CONDITION	MIN	TYP	MAX	UNIT
<b>GATE DRIVE</b>						
Dead Time	1	Monitor body diode conduction on PHASE pin	5		30	ns
<b>BOOTSTRAP PFET</b>						
Forward Voltage		$I(\text{BOOT}) = 10\text{mA}$	100	200	300	mV
<b>UPPER MOSFET</b>						
Static Drain-to-Source On-Resistance		$V_{CC} = 5V, I_D = 12A, T_J = 25^{\circ}C$	7	12	16	m $\Omega$
<b>LOWER MOSFET</b>						
Static Drain-to-Source On-Resistance		$V_{CC} = 5V, I_D = 12A, T_J = 25^{\circ}C$	4	5.3	7	m $\Omega$
<b>LOGIC INPUT AND OUTPUT</b>						
EN High Logic Level			2	-	-	V
EN Low Logic Level			-	-	0.6	V
EN Input Current		$EN = 3.3V$		11		$\mu A$
PGOOD Pull Down Resistance				25	50	$\Omega$

Note 1: Guaranteed by design, not tested in production

Note 2: Upgrade to industrial/MSL2 level applies from date codes 1227 (marking explained on application note AN1132 page 2). Products with prior date code of 1227 are qualified with MSL3 for Consumer Market.

**TYPICAL OPERATING DATA**

Tested with demoboard shown in Figure 7,  $V_{IN} = 12.6V$ ,  $V_{CC} = 5V$ ,  $V_{out} = 1.05V$ ,  $F_s = 300kHz$ ,  $T_A = 25^\circ C$ , no airflow, unless otherwise specified

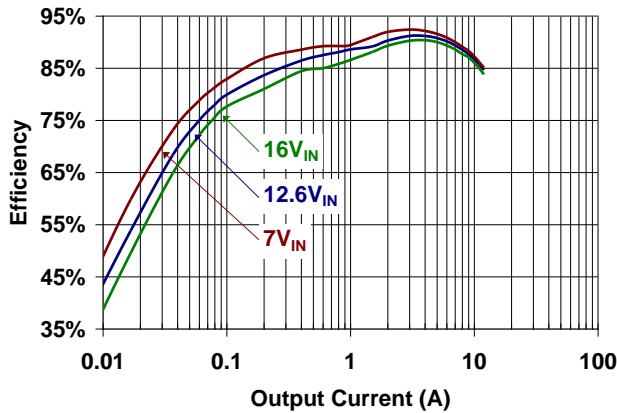


Figure 1. Efficiency vs. Output Current for  $V_{OUT} = 1.05V$ ,  $L = 1.2\mu H$  ( $2.9m\Omega$ )

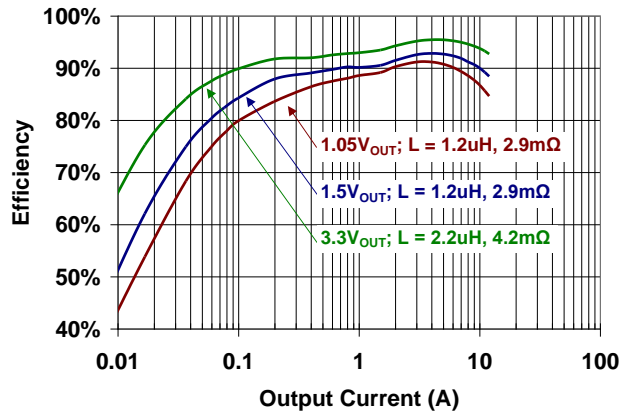


Figure 2. Efficiency vs. Output Current for  $V_{IN} = 12.6V$

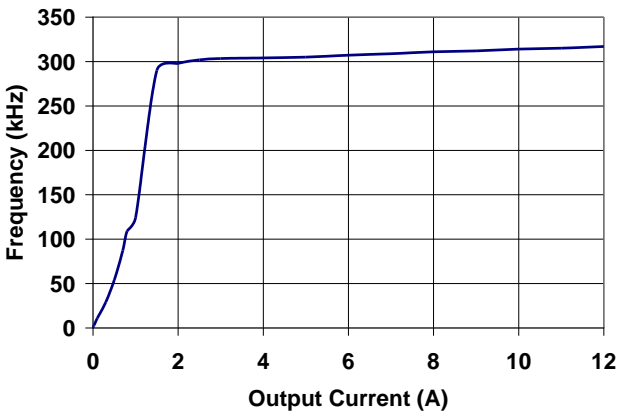


Figure 3. Switching Frequency vs. Output Current

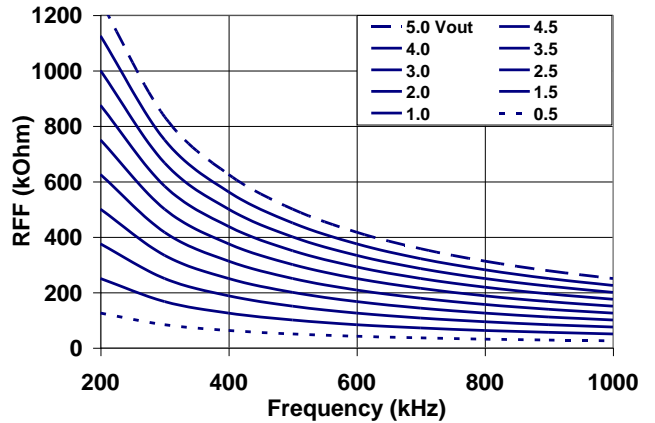


Figure 4. Frequency vs.  $R_{FF}$

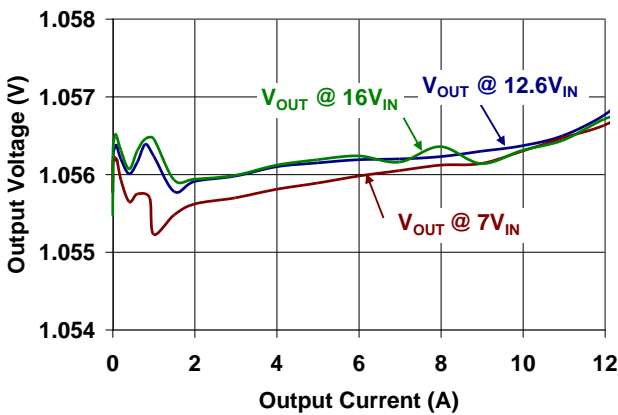


Figure 5. Output Voltage Regulation vs. Output Current

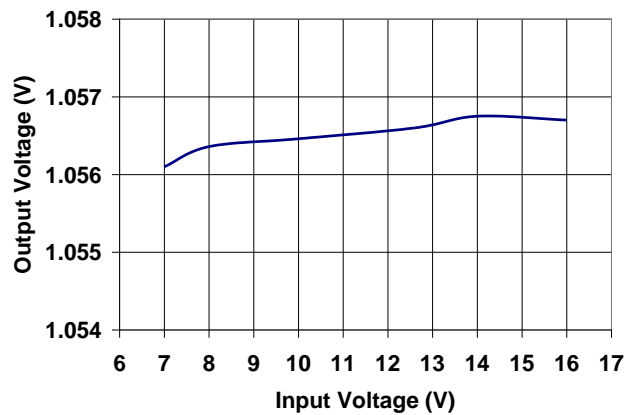


Figure 6. Output Voltage Regulation vs. Input Voltage at  $I_{OUT} = 12A$

TYPICAL APPLICATION CIRCUIT

Demoboard Schematic: VOUT = 1.05V, Fs = 300kHz

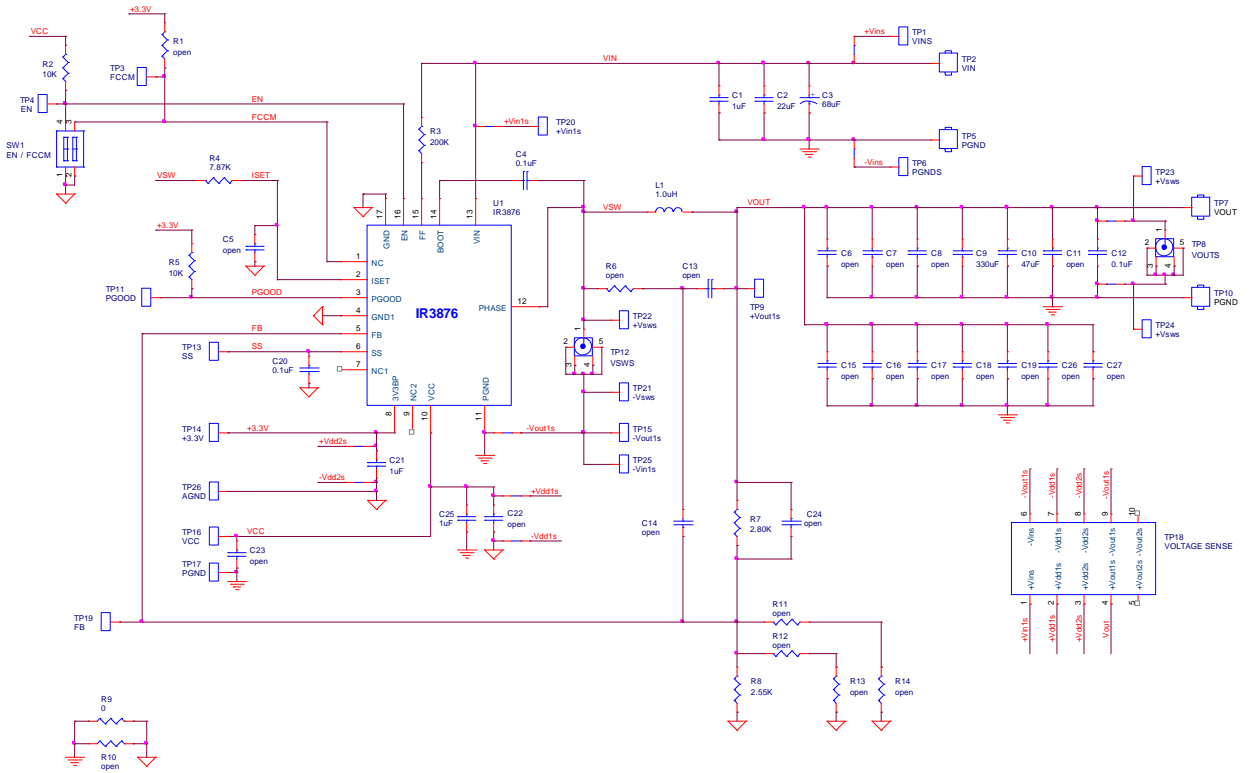


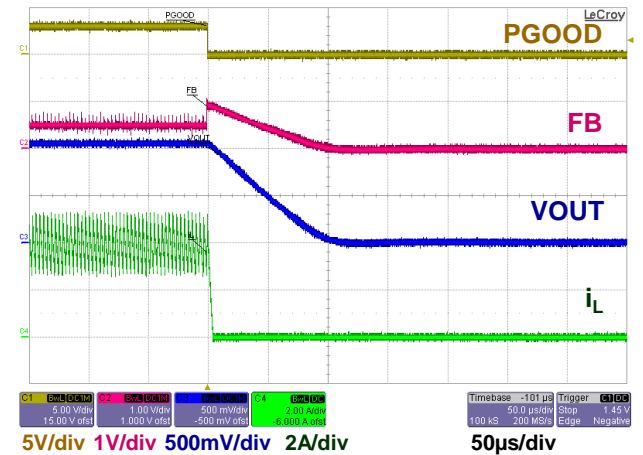
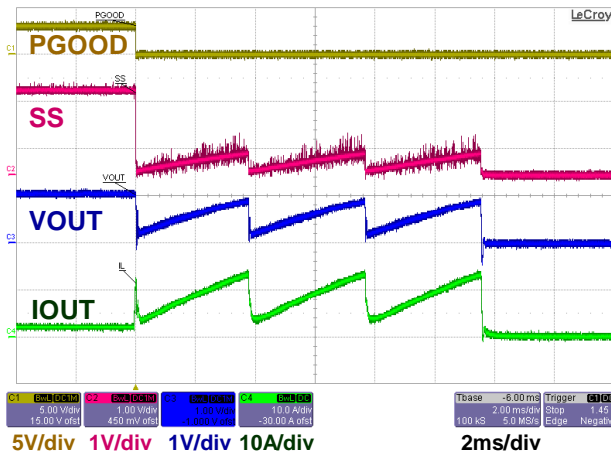
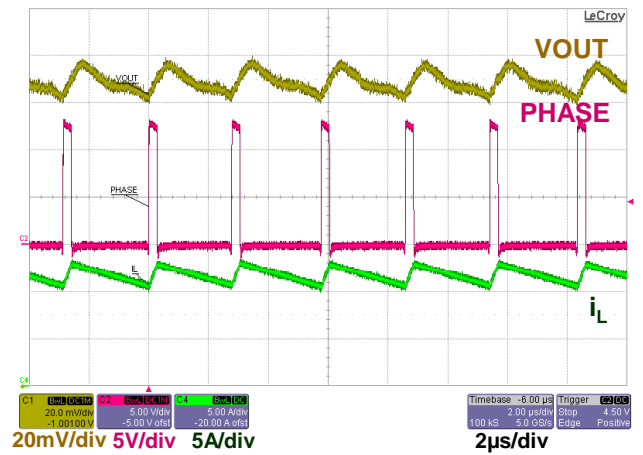
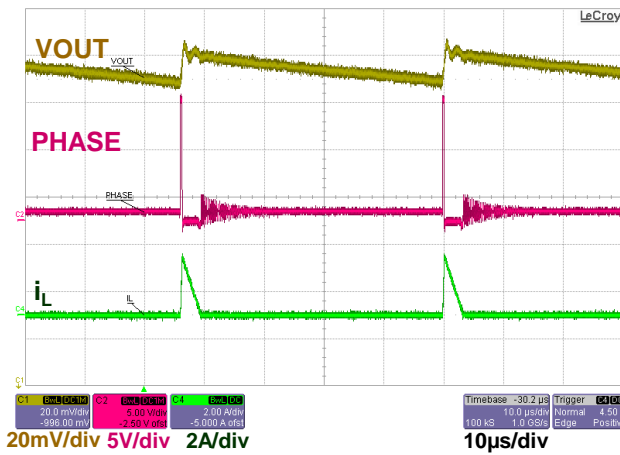
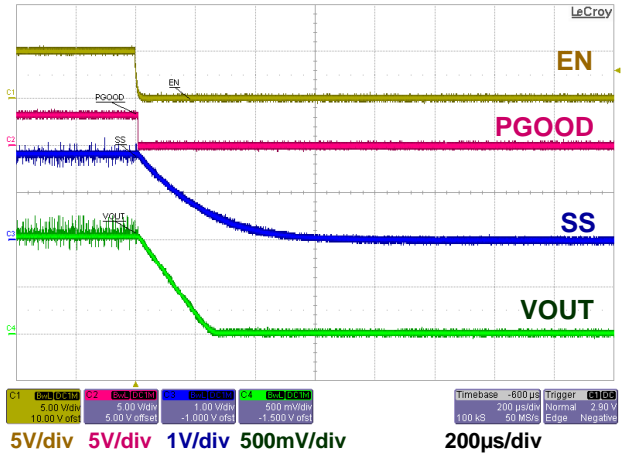
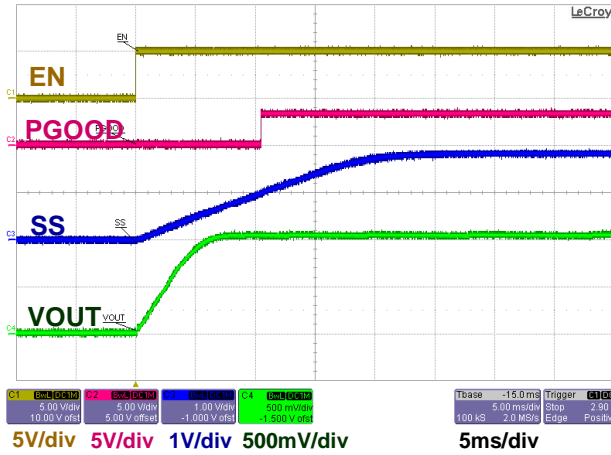
Figure 7. Typical Application Circuit for VOUT = 1.05V, Fs = 300kHz

Bill of Materials

Quantity	Reference	Value	Description	Manufacturer	Part-Number
3	C1, C21, C25	1uF	CAP,CER,1.0uF,25V,X7R,0603	Murata Electronics	GRM188R71E105KA12D
1	C2	22uF	CAP,22uF,25V,CERAMIC,X5R,1210	Panasonic	EEJ-4YB1E226M
1	C3	68uF	CAP,68uF,25V,ELECT,FK,SMD	Panasonic	EEV-FK1E680P
1	C9	330uF	SP-CAP, 330uF, 2V, 4.5mΩ, 20%	Panasonic	EEF-SX0D331E4
1	C10	47uF	CAP,CER,47uF,6.3V,X5R,0805	TDK	C2012X5R0J476M
3	C4, C12, C20	0.1uF	CAP,CER,0.1uF,50V,10%,X7R,0603	TDK	C1608X7R1H104K
1	L1	1uH	INDUCTOR, 1uH, 20A, 2.7mΩ,SMD	CYNTEC	PIMB103E-1R0MS-39
2	R2, R5	10K	RES,10.0kΩ,1/10W,1%,0603,SMD	Vishay/Dale	CRCW060310K0FKEA
1	R9	0	RES,0Ω,1/10W,1%,0603,SMD	Vishay/Dale	CRCW06030000Z0EAHP
1	R3	200K	RES,200kΩ,1/10W,1%,0603,SMD	Vishay/Dale	CRCW0603200KFKFA
1	R4	7.87K	RES,7.87kΩ,1/10W,1%,0603,SMD	Vishay/Dale	CRCW06037K87FKFA
1	R7	2.8K	RES,2.8kΩ,1/10W,1%,0603,SMD	Vishay/Dale	CRCW06032K80FKEA
1	R8	2.55K	RES,2.55kΩ,1/10W,1%,0603,SMD	Vishay/Dale	CRCW06032K55FKEA
1	SW1	SPST	SWITCH, DIP, SPST, SMT	C&K Components	SD02H0SK
1	U1	IR3876	5mm x 6mm QFN	IR	IR3876MPBF

**TYPICAL OPERATING DATA**

Tested with demoboard shown in Figure 7, VIN = 12.6V, VCC = 5V, Vout = 1.05V, Fs = 300kHz, TA = 25°C, no airflow, unless otherwise specified



### TYPICAL OPERATING DATA

Tested with demoboard shown in Figure 7, VIN = 12.6V, VCC = 5V, Vout = 1.05V, Fs = 300kHz, TA = 25°C, no airflow, unless otherwise specified

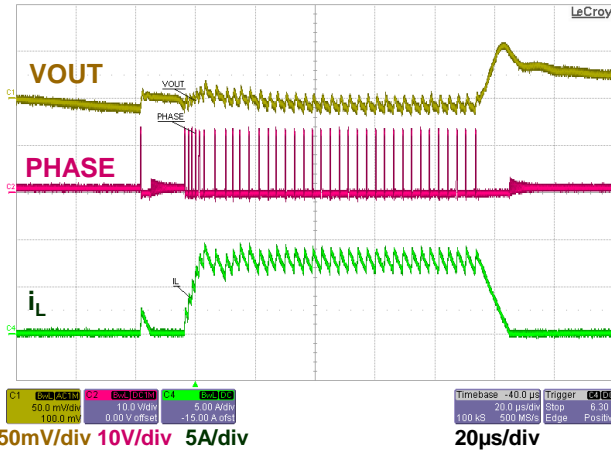


Figure 14: Load Transient 0-8A

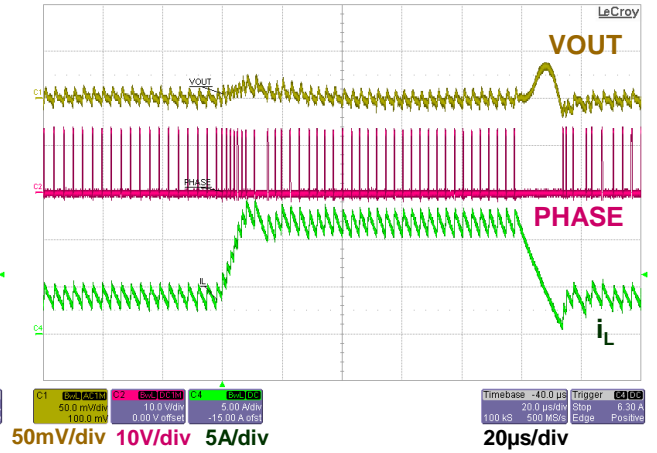


Figure 15: Load Transient 4-12A

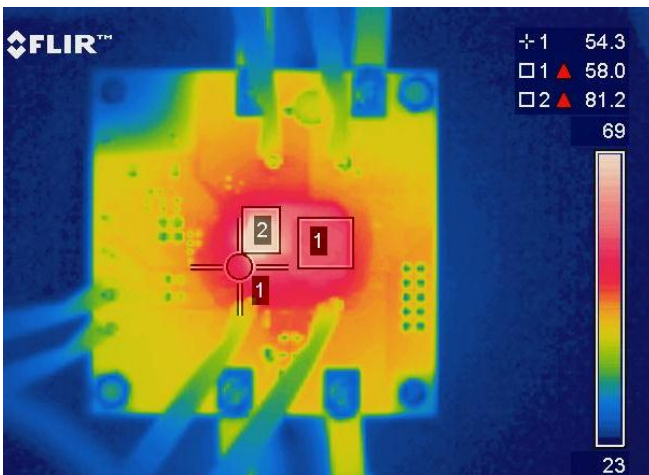


Figure 16: Thermal Image at I<sub>OUT</sub> = 12A  
(IR3876: 81°C, Inductor: 58°C, PCB: 54°C)

## CIRCUIT DESCRIPTION

### PWM COMPARATOR

The PWM comparator initiates a SET signal (PWM pulse) when the FB pin falls below the reference ( $V_{ref}$ ) or the soft start (SS) voltage.

### ON-TIME GENERATOR

The PWM on-time duration is programmed with an external resistor ( $R_{FF}$ ) from the input supply ( $V_{IN}$ ) to the FF pin. The simplified calculation for  $R_{FF}$  is shown in equation 1. The FF pin is held to an internal reference after EN goes HIGH. A copy of the current in  $R_{FF}$  charges a timing capacitor, which sets the on-time duration, as shown in equation 2.

$$R_{FF} = \frac{V_{OUT}}{1V \cdot 20pF \cdot F_{SW}} \quad (1)$$

$$T_{ON} = \frac{R_{FF} \cdot 1V \cdot 20pF}{V_{IN}} \quad (2)$$

### CONTROL LOGIC

The control logic monitors input power sources, sequences the converter through the soft-start and protective modes, and initiates an internal RUN signal when all conditions are met.

$V_{CC}$  and  $3V_{CBP}$  pins are continuously monitored, and the IR3876 will be disabled if the voltage of either pin drops below the falling thresholds.

$EN\_DELAY$  will become HIGH when  $V_{CC}$  and  $3V_{CBP}$  are in the normal operating range and the EN pin = HIGH.

### SOFT START

With EN = HIGH, an internal  $10\mu A$  current source charges the external capacitor ( $C_{SS}$ ) on the SS pin to set the output voltage slew rate during the soft start interval. The soft start time ( $t_{SS}$ ) can be calculated from equation 3.

$$t_{SS} = \frac{C_{SS} \cdot 0.5V}{10\mu A} \quad (3)$$

The feedback voltage tracks the SS pin until SS reaches the 0.5V reference voltage ( $V_{ref}$ ), then feedback is regulated to  $V_{ref}$ .  $C_{SS}$  will continue to be charged, and when SS pin reaches  $V_{SS}$  (see *Electrical Specification*),  $SS\_DELAY$  goes HIGH. With  $EN\_DELAY = LOW$ , the capacitor voltage and SS pin is held to the FB pin voltage. A normal startup sequence is shown in Figure 17.

### PGOOD

The PGOOD pin is open drain and it needs to be externally pulled high. High state indicates that output is in regulation. The PGOOD logic monitors  $EN\_DELAY$ ,  $SS\_DELAY$ , and under/over voltage fault signals. PGOOD is released only when  $EN\_DELAY$  and  $SS\_DELAY = HIGH$  and output voltage is within the OV and UV thresholds.

### PRE-BIAS STARTUP

IR3876 is able to start up into pre-charged output, which prevents oscillation and disturbances of the output voltage.

With constant on-time control, the output voltage is compared with the soft start voltage (SS) or  $V_{ref}$ , depending on which one is lower, and will not start switching unless the output voltage drops below the reference. This scheme prevents discharge of a pre-biased output voltage.

### SHUTDOWN

The IR3876 will shutdown if  $V_{CC}$  is below its UVLO limit. The IR3876 can be shutdown by pulling the EN pin below its lower threshold. Alternatively, the output can be shutdown by pulling the soft start pin below 0.3V.

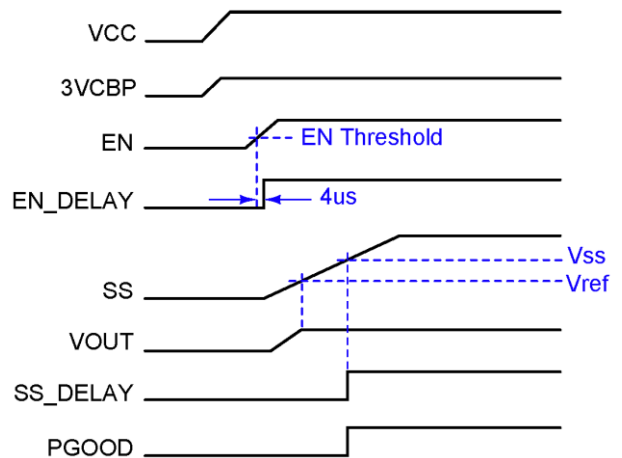


Figure 17. Normal Startup

## CIRCUIT DESCRIPTION

### UNDER/OVER VOLTAGE MONITOR

The IR3876 monitors the voltage at the FB node through a 350ns filter. If the FB voltage is below the under voltage threshold, UV# is set to LOW holding PGOOD to be LOW. If the FB voltage is above the over voltage threshold, OV# is set to LOW, the shutdown signal (SD) is set to HIGH, MOSFET gates are turned off, and PGOOD signal is pulled low. Toggling VCC or EN will allow the next start up. Figure 18 shows PGOOD status change when UV/OV is detected. The over voltage and under voltage thresholds can be found in the *Electrical Specification* section.

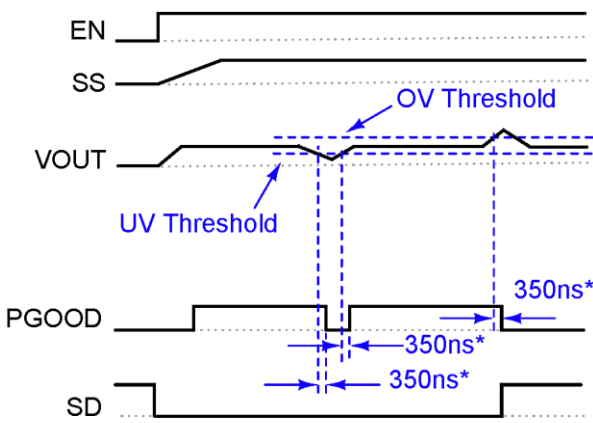


Figure 18(a). Under/Over Voltage Monitor

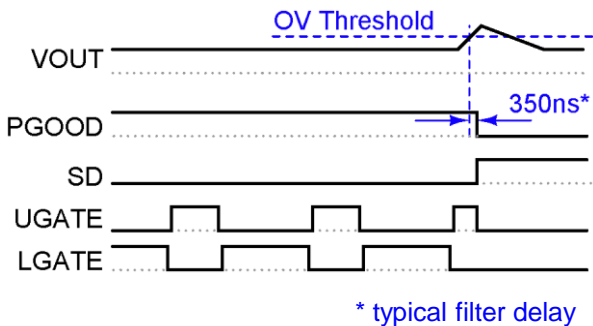


Figure 18(b). Over Voltage Protection

### OVER CURRENT MONITOR

The over-current circuitry monitors the output current during each switching cycle. The voltage across the lower MOSFET, VPHASE, is monitored for over current and zero crossing. The OCP circuit evaluates VPHASE for an over current condition typically 270ns after the lower MOSFET is gated on. This delay functions to filter out switching noise. The minimum lower gate interval allows time to sample VPHASE.

The over current trip point is programmed with a resistor from the ISET pin to PHASE pin, as shown in equation 4, where  $T_j$  is the junction temperature of Q2 at operation conditions, and 0.4 is the temperature coefficient ( $\sim 4000$  ppm/ $^{\circ}\text{C}$ ) of Q2  $R_{\text{DS(on)}}$ . When over current is detected, the output gates are tri-state and SS voltage is pulled to 0V. This initiates a new soft start cycle. If there is a total of four OC events, the IR3876 will disable switching, as shown in Figure 19. Toggling VCC or EN will allow the next start up.

$$R_{\text{SET}} = \frac{R_{\text{DS(on)}} \cdot I_{\text{OC}}}{20 \mu\text{A}} \cdot \left(1 + \frac{T_j - 25}{100} \cdot 0.4\right) \quad (4)$$

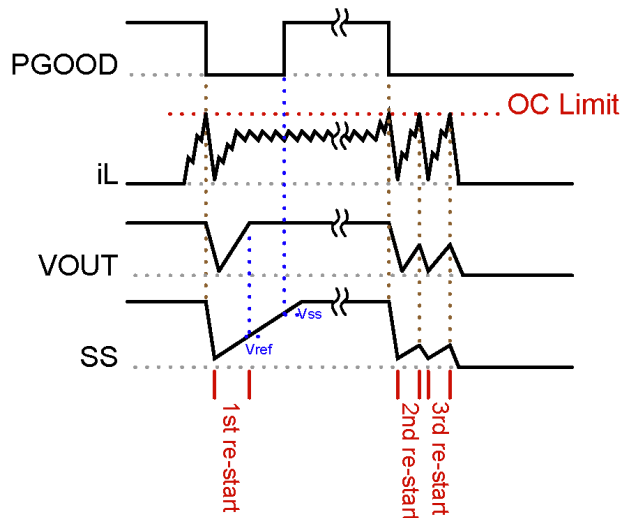


Figure 19. Over Current Protection

## CIRCUIT DESCRIPTION

### GATE DRIVE LOGIC

The gate drive logic features adaptive dead time, diode emulation, and a minimum lower gate interval.

An adaptive dead time prevents the simultaneous conduction of the upper and lower MOSFETs. The lower gate voltage (LGATE) must be below approximately 1V after PWM goes HIGH before the upper MOSFET can be gated on. Also, the upper gate voltage (UGATE), the difference voltage between UGATE and PHASE, must be below approximately 1V after PWM goes LOW before the lower MOSFET can be gated on.

The control MOSFET is gated on after the adaptive delay for PWM = HIGH and the synchronous MOSFET is gated on after the adaptive delay for PWM = LOW. The lower MOSFET is driven 'off' when the signal ZCROSS indicates that the inductor current has reversed as detected by the PHASE voltage crossing the zero current threshold. The synchronous MOSFET stays 'off' until the next PWM falling edge. When the lower peak of inductor current is above zero, a forced continuous current condition is selected. The control MOSFET is gated on after the adaptive delay for PWM = HIGH, and the synchronous MOSFET is gated on after the adaptive delay for PWM = LOW.

The synchronous MOSFET gate is driven on for a minimum duration. This minimum duration allows time to recharge the bootstrap capacitor and allows the current monitor to sample the PHASE voltage.

### STABILITY CONSIDERATIONS

Constant-on-time control is a fast, ripple based control scheme. Unstable operation can occur if certain conditions are not met. The system instability is usually caused by:

- Switching noise coupled to FB input. This causes the PWM comparator to trigger prematurely after the 400ns minimum Q2 on-time. It will result in double or multiple pulses every switching cycle instead of the expected single pulse. Double pulsing can cause higher output voltage ripple, but in most applications it will not affect operation. This can usually be prevented by careful layout of the ground plane and the FB sensing trace.
- Steady state ripple on FB pin being too small. The PWM comparator in IR3876 requires minimum 7mVp-p ripple voltage to operate stably. Not enough ripple will result in similar double pulsing issue described above. Solving this may require using output capacitors with higher ESR.
- ESR loop instability. The stability criteria of constant on-time is:  $ESR \cdot C_{out} > T_{on}/2$ . If ESR is too small that this criteria is violated then sub-harmonic oscillation will occur. This is similar to the instability problem of peak-current-mode control with  $D > 0.5$ . Increasing ESR is the most effective way to stabilize the system, but the price paid is the larger output voltage ripple.
- For applications with all ceramic output capacitors, the ESR is usually too small to meet the stability criteria. In these applications, external slope compensation is necessary to make the loop stable. The ramp injection circuit, composed of R6, C13, and C14, shown in Figure 7 is required. The inductor current ripple sensed by R6 and C13 is AC coupled to the FB pin through C14. C14 is usually chosen between 1 to 10nF, and C13 between 10 to 100nF. R6 should then be chosen such that  $L/DCR = C13 \cdot R6$ .

## COMPONENT SELECTION

Selection of components for the converter is an iterative process which involves meeting the specifications and trade-offs between performance and cost. The following sections will guide one through the process.

### INDUCTOR SELECTION

Inductor selection involves meeting the steady state output ripple requirement, minimizing the switching loss of upper MOSFETs, meeting transient response specifications and minimizing the output capacitance. The output voltage includes a DC voltage and a small AC ripple component due to the low pass filter which has incomplete attenuation of the switching harmonics. Neglecting the inductance in series with the output capacitor, the magnitude of the AC voltage ripple is determined by the total inductor ripple current flowing through the total equivalent series resistance (ESR) of the output capacitor bank.

$$\Delta I = \frac{T_{ON} \cdot (V_{IN} - V_{OUT})}{2 \cdot L} \quad (5)$$

One can use equation 5 to find the required inductance.  $\Delta I$  is defined as shown in Figure 20. The main advantage of small inductance is increased inductor current slew rate during a load transient, which leads to a smaller output capacitance requirement as discussed in the *Output Capacitor Selection* section. The drawback of using smaller inductances is increased switching power loss in upper MOSFET, which reduces the system efficiency and increases the thermal dissipation.

### INPUT CAPACITOR SELECTION

The main function of the input capacitor bank is to provide the input ripple current and fast slew rate current during the load current step up. The input capacitor bank must have adequate ripple current carrying capability to handle the total RMS current. Figure 20 shows a typical input current. Equation 6 shows the RMS input current. The RMS input current contains the DC load current and the inductor ripple current. As shown in equation 5, the inductor ripple current is unrelated to the load current. The maximum RMS input current occurs at the maximum output current. The maximum power dissipation in the input capacitor equals the square of the maximum RMS input current times the input capacitor's total ESR.

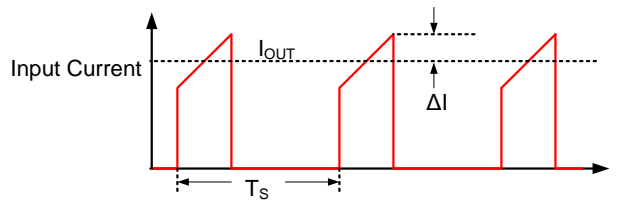


Figure 20. Typical Input Current Waveform.

$$\begin{aligned} I_{IN\_RMS} &= \sqrt{\frac{1}{T_S} \cdot \int_0^{T_S} f^2(t) \cdot dt} \\ &= I_{OUT} \cdot \sqrt{T_{on} \cdot F_S} \cdot \sqrt{1 + \frac{1}{3} \cdot \left(\frac{\Delta I}{I_{OUT}}\right)^2} \quad (6) \end{aligned}$$

The voltage rating of the input capacitor needs to be greater than the maximum input voltage because of high frequency ringing at the phase node. The typical percentage is 25%.

## COMPONENT SELECTION

### OUTPUT CAPACITOR SELECTION

Selection of the output capacitor requires meeting voltage overshoot requirements during load removal, and meeting steady state output ripple voltage requirements. The output capacitor is the most expensive converter component and increases the overall system cost. The output capacitor decoupling in the converter typically includes the low frequency capacitor, such as Specialty Polymer Aluminum, and mid frequency ceramic capacitors.

The first purpose of output capacitors is to provide current when the load demand exceeds the inductor current, as shown in Figure 21. Equation 7 shows the charge requirement for a certain load. The advantage provided by the IR3876 at a load step is to reduce the delay compared to a fixed frequency control method (in microseconds or  $(1-D) \cdot T_s$ ). If the load increases right after the PWM signal goes low, the longest delay will be equal to the minimum lower gate on as shown in the *Electrical Specification* table. The IR3876 also reduces the inductor current slew time, the time it takes for the inductor current to reach equality with the output current, by increasing the switching frequency up to 2.5MHz. The result reduces the recovery time.

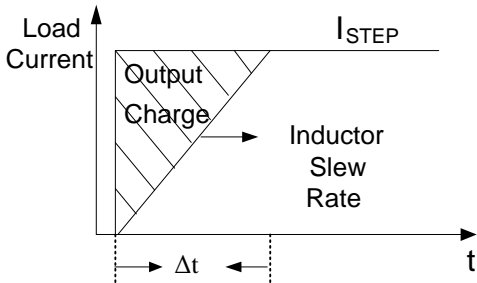


Figure 21. Charge Requirement during Load Step

$$Q = C \cdot V = 0.5 \cdot I_{STEP} \cdot \Delta t \quad (7a)$$

$$C_{OUT} = \frac{1}{V_{DROP}} \left[ \frac{1}{2} \cdot \frac{L \cdot I_{STEP}^2}{(V_{IN} - V_{OUT})} \right] \quad (7b)$$

The output voltage drop,  $V_{DROP}$ , initially depends on the characteristic of the output capacitor.  $V_{DROP}$  is the sum of the equivalent series inductance (ESL) of the output capacitor times the rate of change of the output current and the ESR times the change of the output current.  $V_{ESR}$  is usually much greater than  $V_{ESL}$ . The IR3876 requires a total ESR such that the ripple voltage at the FB pin is greater than 7mV.

The second purpose of the output capacitor is to minimize the overshoot of the output voltage when the load decreases as shown in Figure 22. By using the law of energy before and after the load removal, equation 8 shows the output capacitance requirement for a load step.

$$C_{OUT} = \frac{L \cdot I_{STEP}^2}{V_{OS}^2 - V_{OUT}^2} \quad (8)$$

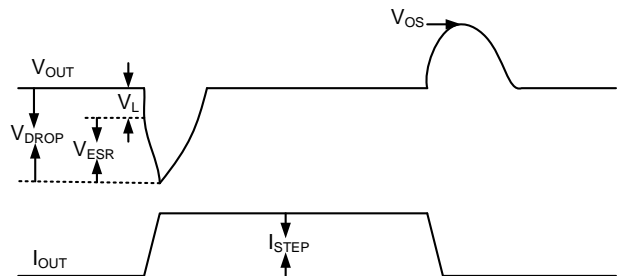


Figure 22. Typical Output Voltage Response Waveform.

### BOOT CAPACITOR SELECTION

The boot capacitor starts the cycle fully charged to a voltage of  $V_B(0)$ .  $C_g$  equals 0.65nF in IR3876. Choose a sufficiently small  $\Delta V$  such that  $V_B(0) - \Delta V$  exceeds the maximum gate threshold voltage to turn on the high side MOSFET.

$$C_{BOOT} = C_g \cdot \left( \frac{V_B(0)}{\Delta V} - 1 \right) \quad (9)$$

Choose a boot capacitor value larger than the calculated  $C_{BOOT}$  in equation 9. Equation 9 is based on charge balance at CCM operation. Usually the boot capacitor will be discharged to a much lower voltage when the circuit is operating in DCM mode at light load, due to much longer Q2 off time and the bias current drawn by the IC. Boot capacitance needs to be increased if insufficient turn-on of Q1 is observed at light load, typically larger than 0.1 $\mu$ F is needed. The voltage rating of this part needs to be larger than  $V_B(0)$  plus the desired derating voltage. Its ESR and ESL needs to be low in order to allow it to deliver the large current and di/dt's which drive MOSFETs most efficiently. In support of these requirements a ceramic capacitor should be chosen.

## DESIGN EXAMPLE

### Design Criteria:

Input Voltage,  $V_{IN}$ , = 7V to 16V  
 Output Voltage,  $V_{OUT}$  = 1.05V  
 Switching Frequency,  $F_s$  = 300KHz  
 Inductor Ripple Current,  $2\Delta I$  = 3A  
 Maximum Output Current,  $I_{OUT}$  = 12A  
 Over Current Trip,  $I_{OC}$  = 18A  
 Overshoot Allowance,  $V_{OS}$  =  $V_{OUT}$  + 50mV  
 Undershoot Allowance,  $V_{DROP}$  = 50mV

Find  $R_{FF}$  :

$$R_{FF} = \frac{1.05V}{1V \cdot 20pF \cdot 300kHz} = 175 k\Omega$$

Pick a standard value 178 k $\Omega$ , 1% resistor.

Find  $R_{SET}$  :

$$R_{SET} = \frac{1.4 \cdot 5.2m\Omega \cdot 18A}{20\mu A} = 6.55 k\Omega$$

The  $R_{DS(on)}$  of the lower MOSFET could be expected to increase by a factor of 1.4 over temperature. Therefore, pick a 6.65k $\Omega$ , 1% standard resistor.

Find a resistive voltage divider for  $V_{OUT}$  = 1.05V:

$$V_{FB} = \frac{R_2}{R_2 + R_1} \cdot V_{OUT} = 0.5V$$

$R_2$  = 2.55k $\Omega$ ,  $R_1$  = 2.80k $\Omega$ , both 1% standard resistors.

Choose the soft start capacitor:

Once the soft start time has chosen, such as 1000us to reach to the reference voltage, a 22nF for  $C_{SS}$  is used to meet 1000 $\mu$ s.

Choose an inductor to meet the design specification:

$$\begin{aligned} L &= \frac{V_{OUT} \cdot (V_{IN} - V_{OUT})}{V_{IN} \cdot 2\Delta I \cdot F_s} \\ &= \frac{1.05V \cdot (16V - 1.05V)}{16V \cdot 3A \cdot 300kHz} \\ &= 1.1\mu H \end{aligned}$$

Choose an inductor with the lowest DCR and AC power loss as possible to increase the overall system efficiency. For instance, choose MPL1055-1R21R manufactured by Delta. The inductance of this part is 1.2 $\mu$ H and has 2.9m $\Omega$  DCR. Ripple current needs to be recalculated using the chosen inductor.

$$\Delta I = \frac{1.05V \cdot (16V - 1.05V)}{2 \cdot 16V \cdot 1.2\mu H \cdot 300kHz} = 1.36A$$

Choose an input capacitor:

$$\begin{aligned} I_{IN\_RMS} &= 12A \cdot \sqrt{\frac{1.05V}{16V}} \cdot \sqrt{1 + \frac{1}{3} \cdot \left(\frac{1.36A}{12A}\right)^2} \\ &= 3.1A \end{aligned}$$

A Panasonic 10 $\mu$ F (ECJ3YB1E106M) accommodates 6 Arms of ripple current at 300KHz. Due to the chemistry of multilayer ceramic capacitors, the capacitance varies over temperature and operating voltage, both AC and DC. One 10 $\mu$ F capacitor is recommended. In a practical solution, one 1 $\mu$ F capacitor is required along with the 10 $\mu$ F. The purpose of the 1 $\mu$ F capacitor is to suppress the switching noise and deliver high frequency current.

Choose an output capacitor:

To meet the undershoot specification, select a set of output capacitors which has an equivalent ESR of 10m $\Omega$  (50mV/5A). To meet the overshoot specification, equation 7 will be used to calculate the minimum output capacitance. As a result, 300 $\mu$ F will be needed for 5A load removal. Combine those two requirements, one can choose a set of output capacitors from manufactures such as Sanyo or Rubycon. A 330 $\mu$ F (2SWZ330M R05) from Rubycon is recommended. This capacitor has 4.5m $\Omega$  ESR which leaves margin for the voltage drop of the ESL during load step up.

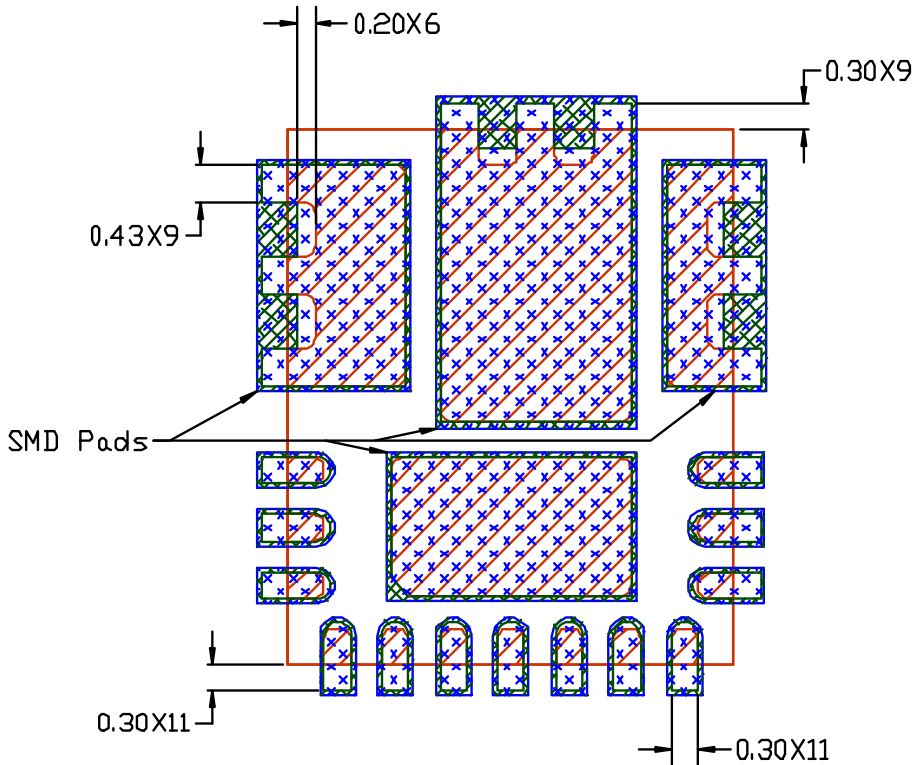


### PCB Metal and Components Placement

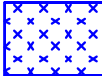


Lead lands (the 13 IC pins) width should be equal to nominal part lead width. The minimum lead to lead spacing should be  $\geq 0.2\text{mm}$  to minimize shorting.

Lead land length should be equal to maximum part lead length + 0.3 mm outboard extension. The outboard extension ensures a large toe fillet that can be easily inspected.

Pad lands (the 4 big pads) length and width should be equal to maximum part pad length and width. However, the minimum metal to metal spacing should be no less than; 0.17mm for 2 oz. Copper or no less than 0.1mm for 1 oz. Copper or no less than 0.23mm for 3 oz. Copper.



All Dimensions In mm

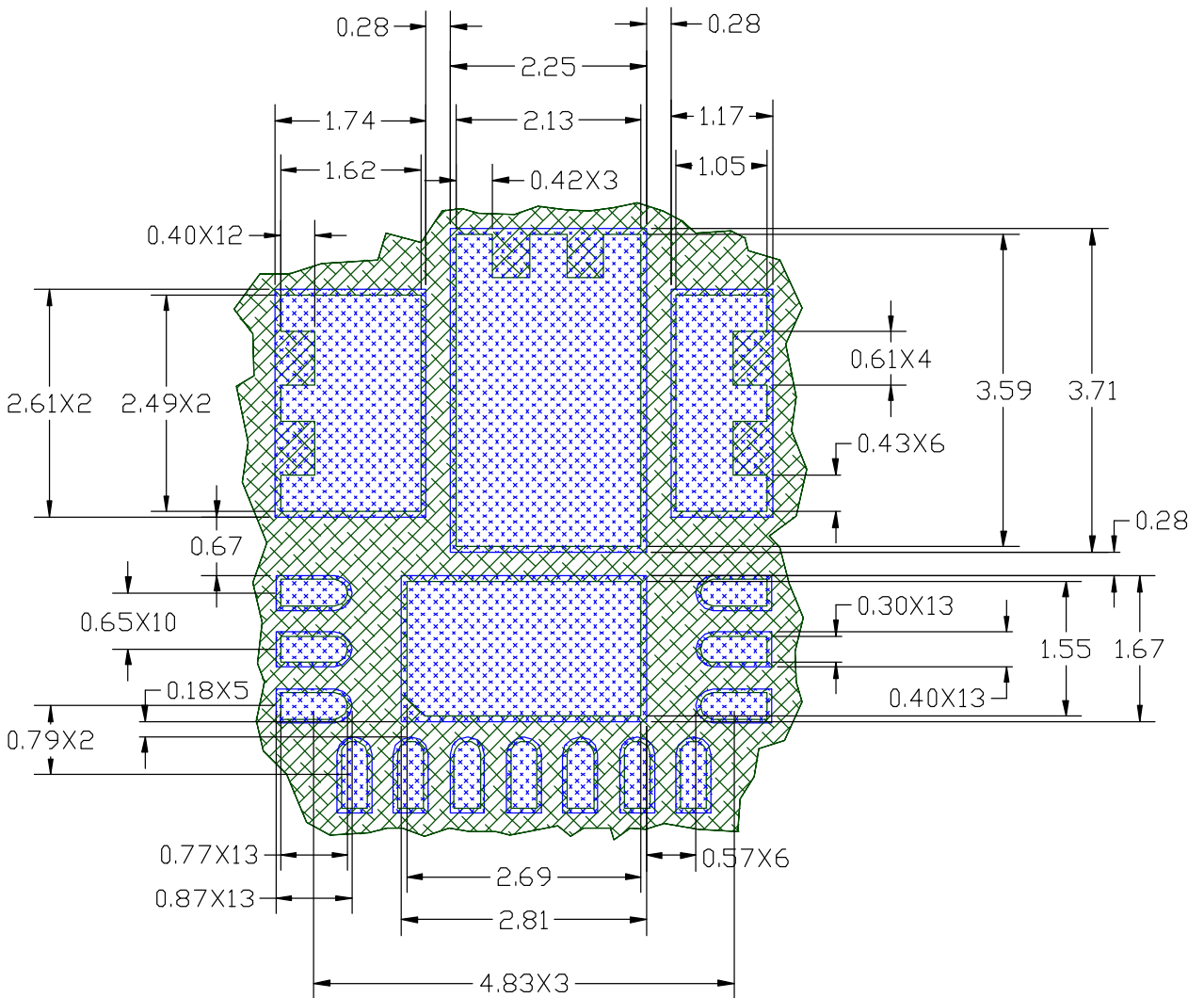
-  PCB Copper
-  PCB Solder Resist
-  Component Pad

**Solder Resist**

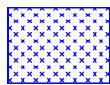
It is recommended that the lead lands are Non Solder Mask Defined (NSMD). The solder resist should be pulled away from the metal lead lands by a minimum of 0.025mm to ensure NSMD pads.

The land pad should be Solder Mask Defined (SMD), with a minimum overlap of the solder resist onto the copper of 0.05mm to accommodate solder resist misalignment.

Ensure that the solder resist in between the lead lands and the pad land is  $\geq 0.15\text{mm}$  due to the high aspect ratio of the solder resist strip separating the lead lands from the pad land.



All Dimensions In mm

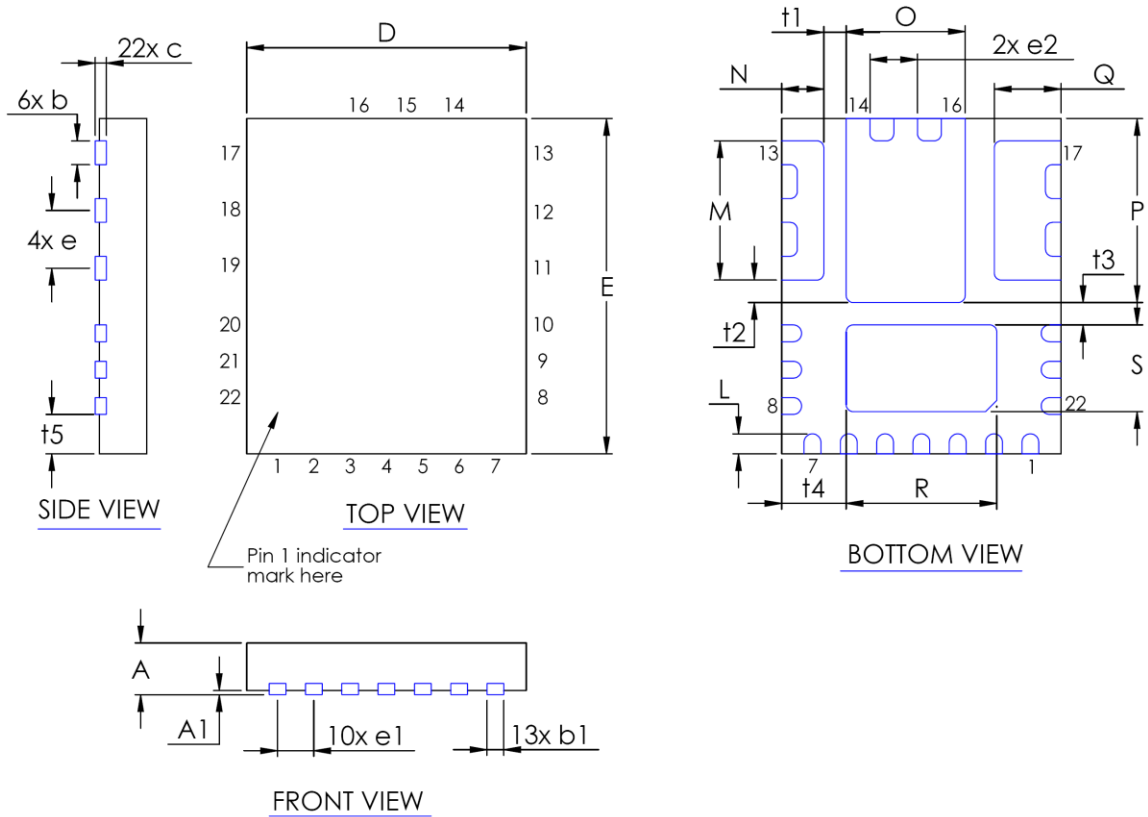


PCB Copper



PCB Solder Resist





DIM	MILIMETERS		INCHES		DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX		MIN	MAX	MIN	MAX
A	0.8	1	0.0315	0.0394	L	0.35	0.45	0.0138	0.0177
A1	0	0.05	0	0.002	M	2.441	2.541	0.0962	0.1001
b	0.375	0.475	0.1477	0.1871	N	0.703	0.803	0.0277	0.0314
b1	0.25	0.35	0.0098	0.1379	O	2.079	2.179	0.0819	0.0858
c	0.203 REF.		0.008 REF.		P	3.242	3.342	0.1276	0.1316
D	5.000 BASIC		1.970 BASIC		Q	1.265	1.365	0.0498	0.05374
E	6.000 BASIC		2.364 BASIC		R	2.644	2.744	0.1042	0.1081
e	1.033 BASIC		0.0407 BASIC		S	1.5	1.6	0.0591	0.063
e1	0.650 BASIC		0.0256 BASIC		t1, t2, t3	0.401 BASIC		0.016 BACIS	
e2	0.852 BASIC		0.0259 BASIC		t4	1.153 BASIC		0.045 BASIC	
					t5	0.727 BASIC		0.0286 BASIC	

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**This product has been designed and qualified for the Industrial Market (Note 2)**

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